

Pb

Free

Large Current External FET Controller Type Switching Regulators Single-output Step-up, High-efficiency Switching Regulator (Controller Type)

BD9763FVM

No.09028EAT07

RoHS

Description

BD9763FVM is a 1-channel high efficiency step-up switching regulator.

It is possible to choose small application space due to its high-speed operation (Max switching frequency 1.2MHz)

Features

- 1) Build-in under voltage lock out circuit.
- 2) High accuracy reference voltage (2.5V±1.0%)
- 3) Establish maximum duty cycle internally.
- 4) CTL/SS terminal for both stand-by and soft-start function. (Soft-start time can be set by external capacitor)
- 5) MSOP8 thin and small package.

Applications

Single-lens reflex cameras, digital video cameras, liquid crystal modules, DVD drive.

●Absolute Maximum Ratings(Ta=25°C)

Parameter	Symbol	Limit	Unit
Supply voltage	Vcc	10	V
Storage temperature range	Tstg	-55 to +150	°C
Power dissipation	Pd	587 *	mW
Junction temperature	Tjmax	+150	°C

IC mounted on a PCB board (70mm x 70mm x 1.6mm, glass epoxy).

Reduced by 4.7mW for each increase in Ta of 1°C over 25°C.

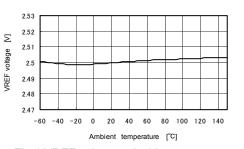
Recommended Operating Conditions

Parameter	Symbol		Unit			
Falameter	Symbol	Min	Тур	Max	Offic	
Supply voltage	Vcc	4	7	9	V	
Oscillating frequency	fosc	100	-	1200	kHz	
Operating temperature range	Topr	-40	-	+85	°C	

●Electrical characteristics (Unless otherwise specified, Ta=25°C, Vcc=7.0V)

lectrical characteristics (Unless oth			Limits		11.29	One Iffer
Parameter	Symbol	Min	Тур	Max	Unit	Condition
[Oscillator]	1					•
Oscillating frequency	fosc	522	600	678	kHz	R _{RT} =24kΩ
Frequency tolerance	FDV	-5	0	5	%	Vcc=4 to 9V
Swing voltage	Vpptr	_	0.5	_	V	
【Stand-by, Soft start】	•			. <u> </u>		
CTL/SS pin source current	ISS	-1.90	-1.00	-0.55	μA	V _{CTL/SS} =1.5V
CTL/SS pin clamp voltage	VSS	2.2	2.4	2.6	V	
CTL threshold voltage	VCTLTH	1.2	1.3	1.4	V	
[PWM comparator]						
0% threshold voltage	D0	1.5	1.6	1.7	V	
Maximum duty cycle	DMAX	80	90	99.5	%	
[Error amplifier]						
Threshold voltage	VIN	0.98	1.00	1.02	V	
Band width	BW	_	3.0	—	MHz	AV=0dB
Voltage gain	Av	_	70	-	dB	
Input bias current	IIB	-150	-70	—	nA	
Maximum output voltage	VCH	2.3	2.4	2.6	V	
Minimum output current	VCL	_	0.03	0.20	V	
Output source current	IOI	-3.1	-1.6	-1.0	mA	V _{FB} =1.0V
Output sink current	100	12	50	125	mA	V _{FB} =1.0V
[Reference voltage]						
Output voltage	VREF	2.475	2.500	2.525	V	I _{VREF} =0mA
Load regulation	∆VREFlo	-	-	10	mV	I _{VREF} =0 to -1mA
Output short current	IVREF	-45	-16	-1	mA	
[Whole device]						
Stand-by current	ICCS	420	610	960	μA	
Circuit current	ICCA	3.4	5.0	7.8	mA	No load
[Output]						
ON resistance	RON	0.9	2.5	8.0	Ω	
Output rise/fall time	Tr/Tf	—	20	—	nsec	Cout=1000pF
Output source current	IOUTSO	_	-0.80	_	А	Ta=-40 to 85°C,VCC=4 to 9V, OUT=0V, rush current
Output sink current	IOUTSI	_	0.85	_	А	Ta=-40 to 85°C,VCC=4 to 9V, OUT=VCC, rush current
【Under voltage lock out】						
	VUT	3.7	3.8	3.9	V	Vcc sweep down
Threshold voltage	001	5.7	0.0	0.0	v	

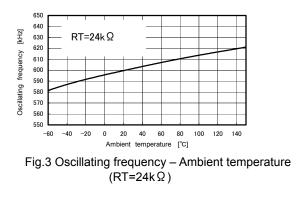
●Reference data (Unless otherwise specified, Ta=25°C)



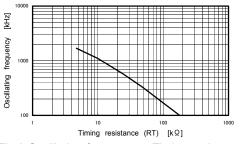
VREF voltage vs. Ambient temperature

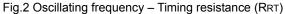
Fig.1 VREF voltage - Ambient temperature





Oscillating frequency vs. Timing resistance





Oscillating frequency vs. Ambient temperature

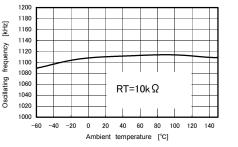


Fig.4 Oscillating frequency – Ambient temperature $(RT=10k \Omega)$

Block diagram

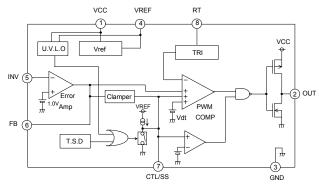


Fig.5

Pin configuration

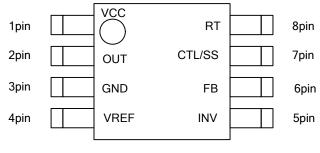


Fig.6

Pin number , Pin name

Pin No.	Pin name	Function
1	VCC	Power supply
2	OUT	FET driver output
3	GND	Ground
4	VREF	Reference voltage (2.5V±1%) output
5	INV	Inverting input of error amplifier
6	FB	Output of error amplifier
7	CTL/SS	Stand-by switch/Soft start capacitor connecting pin
8	RT	Timing resistor connecting pin

Block description

• VOLTAGE REFERENCE(VREF) BLOCK This voltage reference block generates 2.5V internal reference voltage.

OSCILLATOR BLOCK

Oscillator block sets the oscillating frequency adjusted by an external resistance in RT pin. The oscillating frequency can be set within a range of 100~1200kHz. (See the description of how to set the frequency on page6.)

• PWM COMP

The PWM comparator transforms the voltage outputted from error amp to PWM waveform and outputs to FET driver. The maximum duty cycle is limited up to 90%.

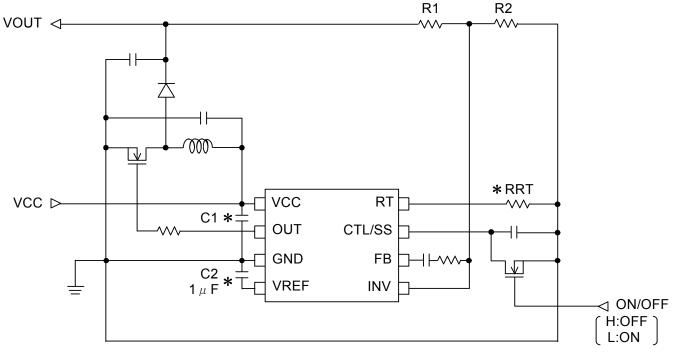
ERROR AMP BLOCK

The error amp block detects the output voltage from the INV pin, amplifies the difference between the detected voltage and the reference voltage, and outputs it to FB pin. The reference voltage is $1V \pm 2\%$.

PROTECTION CIRCUIT BLOCK

The under voltage lock out circuit is activated to shut down the whole circuit when the VCC voltage is up to 3.8V. When the thermal shutdown circuit detects abnormal heating of the chip (150°C), the output becomes off. And the output turns back on when the chip temperature goes down to a specific level.

Application example





Selecting application components

(1) Output inductor

It is recommended to use an inductor which satisfies the following rating current (the following value of current), and also has low DCR. The shield type inductor is preferable.

- I peak = Io·(Vo/VIN) / η + VIN·(VOUT-VIN) / (2·VOUT·L·f) [A]
- [Io: Output Vo: Output voltage VIN: Input voltage η : Efficiency L: Inductance f: Oscillating frequency]
- (2) Output capacitor

It is recommended to use the output capacitor which has the enough margin to maximum rating for output voltage and low fluctuation for temperature. The ripple voltage of the output is influenced by ESR of the output capacitor. Vripple = VIN (VOUT-VIN) / (VOUT-L f) ESR [V]

 $(f >> 1 / (2\pi\sqrt{LC}) \cdot Vo / VIN)$

[Io: Output Vo: Output voltage VIN: Input voltage η : Efficiency L: Inductance C: Output capacitor

f: Oscillating frequency]

(3) FET

- It is recommended to use FETs which satisfy followings and have small Ciss or Qg and ON resistance.
 - D-S Voltage : Over (Output voltage + Vf of Di)
 - G-S Voltage : Over input voltage
 - D-S Current : Over Ipeak at the section of output inductor

(4) Diode

It is recommended to use a schottky diode which satisfies followings and has low forward voltage drop and high switching speed.

Maximum current : Over maximum output current

Direct reverse voltage : Over output voltage

* Please provide sufficient margin in the choice of external components by factoring into the worst case characteristics and temperature range.

(5) Setting the oscillator frequency

Refer to Fig.5 and determine Timing resistor (RRT) when setting the oscillating frequency.

Oscillating frequency vs. Timing resistance

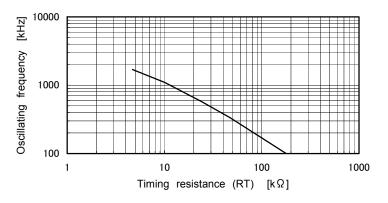


Fig.8 Oscillating frequency - Timing resistance (RRT)

(6) Setting the output voltage

The output voltage is calculated by the following equation. Vo = VINVth · (R1+R2)/R2 [V] R1,R2 : Resistor divider network VINth : Error amp threshold voltage (typ.1V) (but Vo<VIN · 5 because of MAXDUTY Min=80%)

(7) CTL/SS setting the soft start time

The time after CTL/SS is released before the output voltage starts to rise.

t(start) = CCTL · (VDo-Voff)/Iss [S] approximated equation

The time after the output voltage starts up before it reaches the specified output level.

t(soft) = CCTL · (VDUTY-VDo)/Iss [S] approximated equation

VDUTY = VDo+0.5 · (1-VIN/VOUT) [V]

CCTL : CTL/SS–GND capacitande Vdo : 0% duty threshold (Typ 1.6V) Voff : Output off CTL/SS voltage Iss : CTL/SS charge current (Typ 1uA) VDUTY : stabilization operating ON duty.

Timing chart

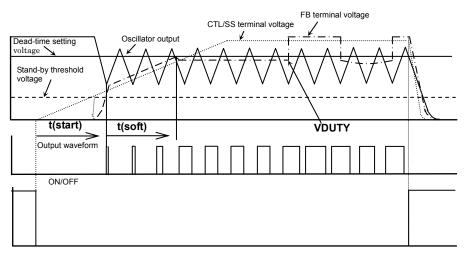
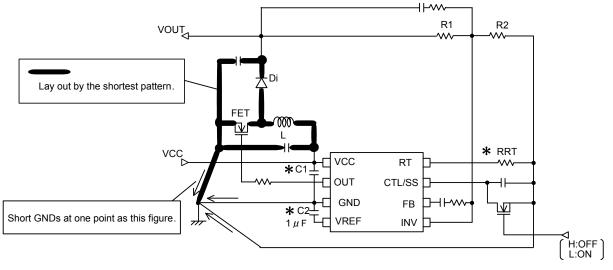


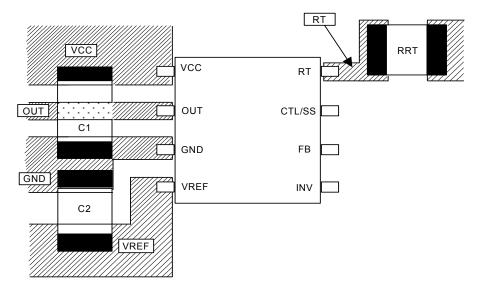
Fig.9

Recommended board patterns



*Place these parts with attention about patterns shown in following Fig.7





C1 : Capacitor terminals have to be close enough to terminals of VCC and GND. It is safe to pass OUT signal line under C1.

- C2 : Capacitor terminals have to be close enough to terminals of VREF and GND.
- R1 : Pattern area has to be small enough to reduce parasitic capacitance of RT terminal.

Fig.11 Recommended board patterns

●I/O Equivalent Circuit

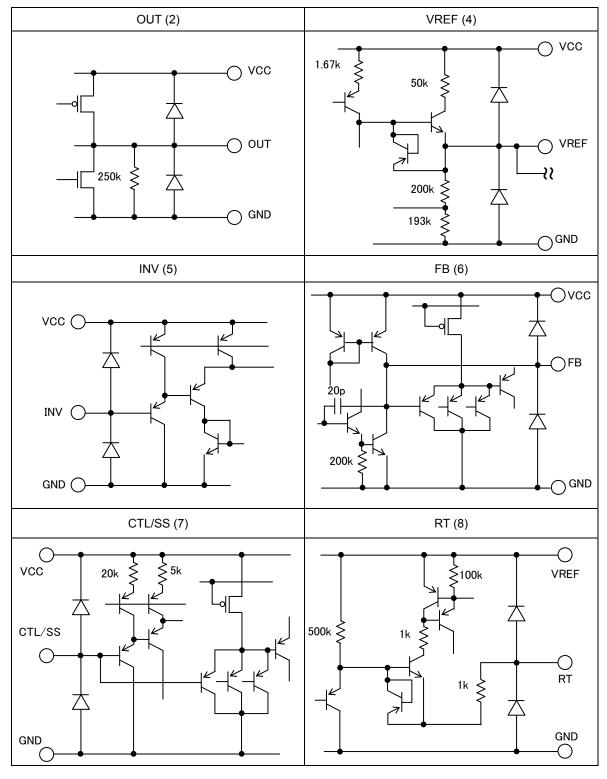


Fig.12

Operation Notes

(1) Absolute maximum ratings

Use of the IC in excess of absolute maximum ratings such as the applied voltage or operating temperature range may result in IC deterioration or damage. Assumptions should not be made regarding the state of the IC(short mode or open mode) when such damage is suffered. A physical safety measure such as fuse should be implemented when use of the IC in a special mode where the absolute maximum ratings may be exceeded is anticipated.

(2) GND potential

Ensure a minimum GND pin potential in all operating conditions. In addition, ensure that no pins other than the GND pin. Carry a voltage lower then or equal to the GND pin, including during actual transient phenomena.

(3) Thermal design

Use a thermal design that allows for a sufficient margin in light of the power dissipation (Pd) in actual operating conditions.

(4) Inter-pin shorts and mounting errors

Use caution when orienting and positioning the IC for mounting on printed circuit boards. Improper mounting may result in damage to the IC. Shorts between output pins or between output pins and the power supply and GND pin caused by the presence of a foreign object may result in damage to the IC.

- (5) Operation in a strong electromagnetic field Use caution when using the IC in the presence of a strong electromagnetic field as doing so may cause the IC to malfunction.
- (6) Thermal shutdown circuit (TSD circuit)

This IC incorporates a built-in thermal shutdown circuit (TSD circuit). The TSD circuit designed only to shut the IC off to prevent runaway thermal operation.

do not continue to use the IC after operating this circuit or use the IC in an environment where the operation of the thermal shutdown circuit is assumed.

(7) Testing on application boards

When testing the IC on an application board, connecting a capacitor to pin with low impedance subjects the IC to stress. Always discharge capacitors after each process or step. Ground the IC during assembly steps as an antistatic measure, and use similar caution when transporting or storing the IC. Always turn the IC's power supply off before connecting it to or removing it from a jig or fixture the inspection process.

(8) Common impedance

Power supply and ground wiring should reflect consideration of the need to lower common impedance and minimize ripple as much as possible (by making wiring as short and thick as possible or rejecting ripple by incorporating inductance and capacitance).

(9) Applications with modes that reverse VCC and pin potentials may cause damage to internal IC circuits.

For example, such damage might occur when VCC is shorted with the GND pin while an external capacitor is charged. It is recommended to insert a diode for preventing back current flow in series with VCC or bypass diodes between VCC and each pin.

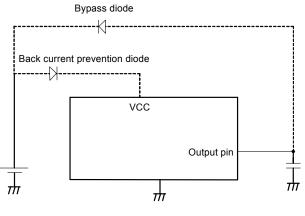


Fig.13

(10) Timing resistor

Timing resistor connected between RT and GND, has to be placed near RT terminal (8pin). And pattern has to be short Enough.

(11) IC pin input

This monolithic IC contains P + isolation and PCB layers between adjacent elements in order to keep them isolated. P/N junctions are formed at the intersection of these P layers with the N layers of other elements to create a variety of parasitic elements.

For example, when a resistor and transistor are connected to pins as shown in Fig.14,

Othe P/N junction functions as a parasitic diode when GND > (Pin A) for the resistor or GND > (Pin B) for the transistor (NPN).

OSimilarly, when GND > (Pin B) for the transistor (NPN), the parasitic diode described above combines With the N layer of other adjacent elements to operate as a parasitic NPN transistor.

The formation of parasitic elements as a result of the relationships of the potentials of different pins is an inevitable result of the IC's architecture. The operation of parasitic elements can cause interference with circuit operation as well as IC malfunction and damage. For these reasons, it is necessary to use caution so that the IC is not used in away that will trigger the operation of parasitic elements, such as by the application of voltage lower than the GND (PCB) voltage to input and output pins.

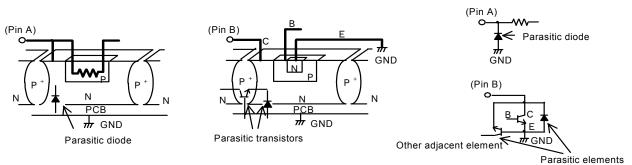
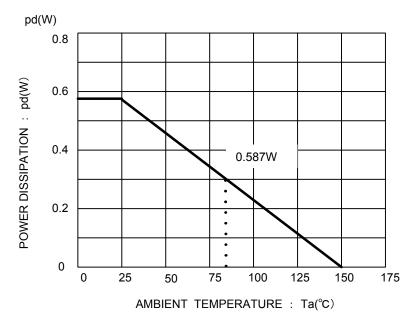


Fig.14

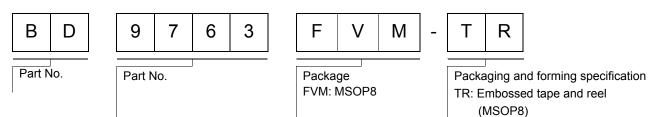
Power Dissipation Reduction



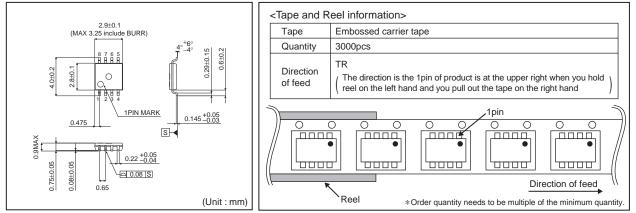
IC mounted on a ROHM standard board (70mm x 70mm x 1.6mm, glass epoxy)

Fig.15

Ordering part number



MSOP8



	Notes
	g or reproduction of this document, in part or in whole, is permitted without the ROHM Co.,Ltd.
The conter	t specified herein is subject to change for improvement without notice.
"Products"	nt specified herein is for the purpose of introducing ROHM's products (hereinafte). If you wish to use any such Product, please be sure to refer to the specifications be obtained from ROHM upon request.
illustrate th	of application circuits, circuit constants and any other information contained herein the standard usage and operations of the Products. The peripheral conditions mus to account when designing circuits for mass production.
However, s	was taken in ensuring the accuracy of the information specified in this document should you incur any damage arising from any inaccuracy or misprint of such , ROHM shall bear no responsibility for such damage.
examples implicitly, a other parti	cal information specified herein is intended only to show the typical functions of and of application circuits for the Products. ROHM does not grant you, explicitly of iny license to use or exercise intellectual property or other rights held by ROHM and es. ROHM shall bear no responsibility whatsoever for any dispute arising from the intechnical information.
equipment	cts specified in this document are intended to be used with general-use electronic or devices (such as audio visual equipment, office-automation equipment, commu vices, electronic appliances and amusement devices).
The Produc	cts specified in this document are not designed to be radiation tolerant.
	IM always makes efforts to enhance the quality and reliability of its Products, a ay fail or malfunction for a variety of reasons.
against the failure of a shall bear	sure to implement in your equipment using the Products safety measures to guard e possibility of physical injury, fire or any other damage caused in the event of the ny Product, such as derating, redundancy, fire control and fail-safe designs. ROHM no responsibility whatsoever for your use of any Product outside of the prescribed of in accordance with the instruction manual.
system wh may result instrument fuel-contro any of the	cts are not designed or manufactured to be used with any equipment, device o ich requires an extremely high level of reliability the failure or malfunction of which in a direct threat to human life or create a risk of human injury (such as a medica , transportation equipment, aerospace machinery, nuclear-reactor controller ller or other safety device). ROHM shall bear no responsibility in any way for use o Products for the above special purposes. If a Product is intended to be used for an al purpose, please contact a ROHM sales representative before purchasing.
be controll	nd to export or ship overseas any Product or technology specified herein that may ed under the Foreign Exchange and the Foreign Trade Law, you will be required to ense or permit under the Law.



Thank you for your accessing to ROHM product informations. More detail product informations and catalogs are available, please contact us.

ROHM Customer Support System

http://www.rohm.com/contact/